## **TX14T**

### High accurate, reliable

(LV)HCMOS or Sine wave TCXO with internal trimmer

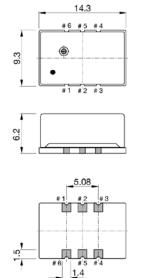


Frequency range	10.000 to 100.	000	MHz	
Standard frequencies	10, 20, 25, 32, , 38.8	38, 40	, 48, 50, 60, 10	0 MHz
Frequency stability:				
vs. temperature referenced to (FMAX+FMIN)/2	≤ ±0.5 ppm	ove	er -40 to +85 °C	(*)
vs. supply voltage changes referenced to frequency at nominal supply	≤ ±0.05 ppm	±5 '	%	
vs. load changes referenced to frequency at nominal load	≤ ±0.05 ppm	±10	%	
vs. aging @ +40 °C	≤ ±1.0 ppm	1 <sup>st</sup> )	/ear	
G-sensitivity	2.0 ppb/g	per	axis	
Short term stability ADEV	< 1*10 <sup>-10</sup>	τ =	1.0 s	
Frequency tolerance ex factory	0 ~ +1.0 ppm	@ -	+25 °C	
Supply voltage	+3.3 V or 5.0 V			(*)
Output signal	Sine wave		(LV)HCMOS	(*)
Frequency range	20 to 100 MHz		10 to 100 MHz	
Output level	+3 to +6 dBm		VOH > 0.9*Vcc / \	/OL < 0.1*Vcc
Output load	50 Ω		15 pF max.	
Current consumption	< 15 mA		< 10 mA	
Frequency adjustment (trimming)	≥ 5 ppm	by int	ernal trimmer	
Phase noise (typical value for 40 MHz)	-85 dBc/Hz -112 dBc/Hz -140 dBc/Hz -150 dBc/Hz -154 dBc/Hz -155 dBc/Hz	00000	10 Hz 100 Hz 1 kHz 10 kHz 100 kHz 1 MHz	
Operating temperature range	-40 ~ +85 °C			(*)
Reflow profiles as per IPC/JEDEC J-STD-020C	≤ 245 °C over 10 s max.			

### (\*) See available options on page #2

Note: Pin function

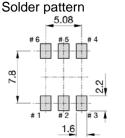
Unless otherwise specified conditions are @+25 °C

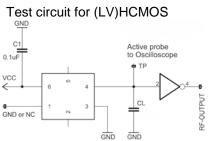


GND or NC # 2 NC or GND #3 **GND** 

# 4 RF output # 5 NC or GND # 6 Vcc

Test circuit for Sine wave





2011/65/EU RoHS compliant

GND

50

GND

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GND

GND or NC

vcc ←

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QuartzCom AG reserves the right to make spec changes to this product

## **TX14T**

# **High accurate, reliable** (LV)HCMOS or Sine wave TCXO with internal trimmer



## **Ordering code**

#### 

Oscillator type	(1) Output signal	(2) Supply voltage	(3) Operating temperature
TX = TCXO	H = (LV)CMOS S = Sine wave	33 = 3.3 V 50 = 5.0 V	EK = -0 to +70 °C JK = -20 to +70 °C NN = -40 to +85 °C
		(4) Frequency stability	NP = -40 to +95 °C NR = -40 to +105 °C
		$u10 = \pm 0.10 \text{ ppm}$ $u25 = \pm 0.25 \text{ ppm}$	$QN = -55 \text{ to } +85 ^{\circ}\text{C}$
		$u50 = \pm 0.50 \text{ ppm}$	
		$1u0 = \pm 1.00 \text{ ppm}$ $1u5 = \pm 1.50 \text{ ppm}$	

### Frequency stability vs. temperature

ppm	≤± 0.10	≤± 0.25	≤± 0.50	≤± 1.00	≤± 1.50
-20 to +70 °C	Δ	0	0	0	0
-40 to +85 °C	Δ	Δ	0	0	0
-40 to +95 °C	Δ	Δ	Δ	Δ	0
-40 to +105 °C	Δ	Δ	Δ	Δ	Δ
-55 to +85 °C	Х	Х	Δ	Δ	Δ

Δ Ask factory	
O Available	
X Not available	

### Absolute max. ratings

Supply voltage (Vcc)	6.0 V
Storage temperature range	-55 ~ +105 °C
Control voltage (Vc)	0 / Vcc

2011/65/EU RoHS compliant

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